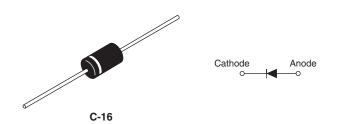
**Vishay Semiconductors** 

# Schottky Rectifier, 3.3 A



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| PRODUCT SUMMARY                  |                      |  |  |  |  |
|----------------------------------|----------------------|--|--|--|--|
| Package                          | DO-201AD (C-16)      |  |  |  |  |
| I <sub>F(AV)</sub>               | 3.3 A                |  |  |  |  |
| V <sub>R</sub>                   | 90 V, 100 V          |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | See Electrical table |  |  |  |  |
| I <sub>RM</sub> max.             | 3.0 mA at 125 °C     |  |  |  |  |
| T <sub>J</sub> max.              | 150 °C               |  |  |  |  |
| Diode variation                  | Single die           |  |  |  |  |
| E <sub>AS</sub>                  | 3.0 mJ               |  |  |  |  |

### **FEATURES**

- Low profile, axial leaded outline
- High frequency operation
- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



HALOGEN

**FREE** Available

- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for commercial level
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

### DESCRIPTION

The VS-31DQ... axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection

| MAJOR RATINGS AND CHARACTERISTICS |                               |             |       |  |  |  |
|-----------------------------------|-------------------------------|-------------|-------|--|--|--|
| SYMBOL                            | CHARACTERISTICS               | VALUES      | UNITS |  |  |  |
| I <sub>F(AV)</sub>                | Rectangular waveform          | 3.3         | A     |  |  |  |
| V <sub>RRM</sub>                  |                               | 90/100      | V     |  |  |  |
| I <sub>FSM</sub>                  | t <sub>p</sub> = 5 μs sine    | 210         | A     |  |  |  |
| V <sub>F</sub>                    | 3 Apk, T <sub>J</sub> = 25 °C | 0.85        | V     |  |  |  |
| TJ                                |                               | - 40 to 150 | °C    |  |  |  |

| VOLTAGE RATINGS                         |                  |           |              |           |              |       |  |  |
|---|------------------|-----------|--------------|-----------|--------------|-------|--|--|
| PARAMETER                               | SYMBOL           | VS-31DQ09 | VS-31DQ09-M3 | VS-31DQ10 | VS-31DQ10-M3 | UNITS |  |  |
| Maximum DC reverse voltage              | V <sub>R</sub>   |           |              |           |              |       |  |  |
| Maximum working peak<br>reverse voltage | V <sub>RWM</sub> | 90        | 90           | 100       | 100          | V     |  |  |

| ABSOLUTE MAXIMUM RATINGS                               |                    |   |   |       |    |  |  |
|--|--------------------|---|---|-------|----|--|--|
| PARAMETER  | SYMBOL             | TEST CONDI  | VALUES  | UNITS |    |  |  |
| Maximum average forward current<br>See fig. 4          | I <sub>F(AV)</sub> | 50 % duty cycle at $T_L$ = 108 °C, rectangular waveform   |   | 3.3   |    |  |  |
| Maximum peak one cycle<br>non-repetitive surge current |                    | 5 $\mu s$ sine or 3 $\mu s$ rect. pulse   | Following any rated load condition and with rated | 210   | A  |  |  |
| See fig. 6   | IFSM               | 10 ms sine or 6 ms rect. pulse  | V <sub>RRM</sub> applied                          | 34    |    |  |  |
| Non-repetitive avalanche energy                        | E <sub>AS</sub>    | T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 6 mH   |   | 3.0   | mJ |  |  |
| Repetitive avalanche current                           | I <sub>AR</sub>    | Current decaying linearly to zero in 1 $\mu$ s<br>Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical |   | 0.5   | А  |  |  |

Revision: 19-Sep-11

Document Number: 93321

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| ELECTRICAL SPECIFICATIONS       |                                |   |                                 |        |       |  |
|---------------------------------|--------------------------------|---|---------------------------------|--------|-------|--|
| PARAMETER                       | SYMBOL                         | TEST CO   | NDITIONS                        | VALUES | UNITS |  |
|                                 | V <sub>FM</sub> <sup>(1)</sup> | 3 A   | T.I = 25 °C                     | 0.85   | V     |  |
| Maximum forward voltage drop    |                                | 6 A   | 1j=23 0                         | 0.97   |       |  |
| See fig. 1                      |                                | 3 A   | T 105 %O                        | 0.69   |       |  |
|                                 |                                | 6 A   | T <sub>J</sub> = 125 °C         | 0.80   |       |  |
| Maximum reverse leakage current | I <sub>BM</sub> <sup>(1)</sup> | T <sub>J</sub> = 25 °C                                      | $V_{\rm B}$ = Rated $V_{\rm B}$ | 1      | mA    |  |
| See fig. 4                      | IRM ( )                        | T <sub>J</sub> = 125 °C                                     | $v_{\rm R} = naleu v_{\rm R}$   | 3      |       |  |
| Typical junction capacitance    | CT                             | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C |                                 | 110    | pF    |  |
| Typical series inductance       | L <sub>S</sub>                 | Measured lead to lead 5 mm from package body 9.0            |                                 |        | nH    |  |
| Maximum voltage rate of charge  | dV/dt                          | Rated V <sub>R</sub> 10 000 V/                              |                                 |        | V/µs  |  |

### Note

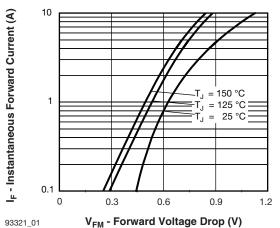
<sup>(1)</sup> Pulse width < 300  $\mu$ s, duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS             |  |                                     |             |       |  |  |
|---|--|-------------------------------------|-------------|-------|--|--|
| PARAMETER                                       | SYMBOL   | TEST CONDITIONS                     | VALUES      | UNITS |  |  |
| Maximum junction and storage temperature range  | T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub> |                                     | - 40 to 150 | °C    |  |  |
| Maximum thermal resistance, junction to ambient | R <sub>thJA</sub>                                | DC operation<br>Without cooling fin | 80          | °C/W  |  |  |
| Typical thermal resistance, junction to lead    | R <sub>thJL</sub>                                | DC operation                        | 15          | °C/W  |  |  |
| Approvimeto weight                              |  |                                     | 1.2         | g     |  |  |
| Approximate weight                              |  |                                     | 0.042       | oz.   |  |  |
| Marking device                                  |  |                                     | 31DQ09      |       |  |  |
|   |  | Case style C-16                     | 31DQ10      |       |  |  |

#### Note

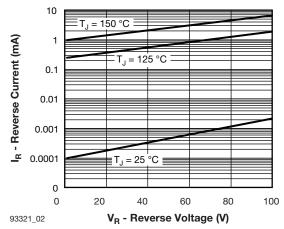
(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

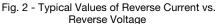
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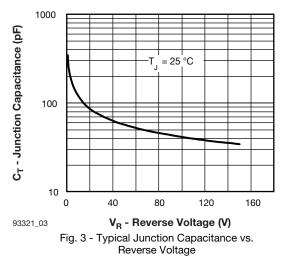


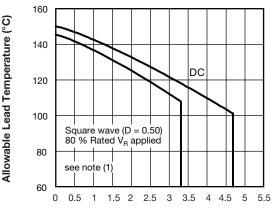
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Fig. 1 - Maximum Forward Voltage Drop Characteristics









93321\_04 **I<sub>F(AV)</sub> - Average Forward Current (A)** Fig. 4 - Maximum Allowable Lead Temperature vs. Average Forward Current

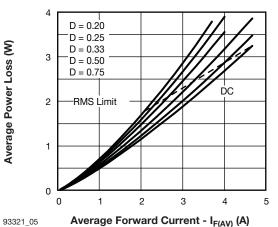
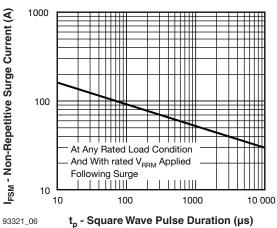


Fig. 5 - Forward Power Loss Characteristics





#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJL}$ ;

Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$ 

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### **ORDERING INFORMATION TABLE**

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| Device code | VS-                                     | 31   | D  | Q   | 10                               | TR | -M3     |                              |
|-------------|---|--|--|---|----------------------------------|----|---------|------------------------------|
|             |   | 2  | 3  | 4   | 5                                | 6  | 7       | I                            |
|             | 1 -   2 -   3 -   4 -   5 -   6 -   7 - | 31 =<br>D = 1<br>Q =<br>10 =<br>• TR<br>• No<br>Envi | Current<br>DO-201<br>Schottky<br>Voltage<br>= Tape<br>ne = Bu<br>ronment | iconduct<br>t Rating,<br>packag<br>y Q ser<br>ratings<br>and ree<br>lk packa<br>tal digit<br>ad (Pb)- | , 3.3 A<br>e<br>ries<br>el packa | ge | complia | 09 = 90 V<br>10 = 100 V      |
|             |   |  |  | , ,   |                                  |    | •       | d terminations lead (Pb)-fre |

| ORDERING INFORMATION (Example) |                  |                        |                       |  |  |  |
|--------------------------------|------------------|------------------------|-----------------------|--|--|--|
| PREFERRED P/N                  | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION |  |  |  |
| VS-31DQ09                      | 500              | 500                    | Bulk                  |  |  |  |
| VS-31DQ09TR                    | 1200             | 1200                   | Tape and reel         |  |  |  |
| VS-31DQ09-M3                   | 500              | 500                    | Bulk                  |  |  |  |
| VS-31DQ09TR-M3                 | 1200             | 1200                   | Tape and reel         |  |  |  |
| VS-31DQ10                      | 500              | 500                    | Bulk                  |  |  |  |
| VS-31DQ10TR                    | 1200             | 1200                   | Tape and reel         |  |  |  |
| VS-31DQ10-M3                   | 500              | 500                    | Bulk                  |  |  |  |
| VS-31DQ10TR-M3                 | 1200             | 1200                   | Tape and reel         |  |  |  |

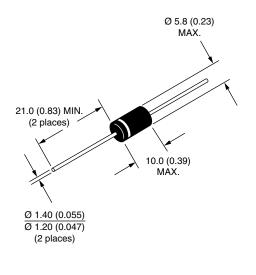
| LINKS TO RELATED DOCUMENTS |                          |  |  |  |  |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions                 | www.vishay.com/doc?95242 |  |  |  |  |
| Part marking information   | www.vishay.com/doc?95304 |  |  |  |  |
| Packaging information      | www.vishay.com/doc?95338 |  |  |  |  |
| SPICE model                | www.vishay.com/doc?95300 |  |  |  |  |

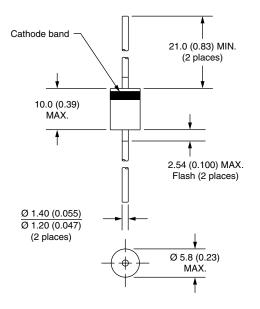




Axial DO-201AD (C-16)

### **DIMENSIONS** in millimeters (inches)







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